



## Ph.D. Course in Materials Science and Nanotechnology

University of Milano-Bicocca, Department of Materials Science, via Cozzi 55, 20125 Milano

## May 21, 2018 – 11.30 a.m. Seminar room - Department of Materials Science U5

## Fabrizio Moro

Department of Physics, Linköping University, Sweden

## Tuning optical and magnetic properties of PbS colloidal quantum dots by doping with Mn2+ transition metal ions

The controlled incorporation of magnetic dopants in quantum dots (QDs) is a challenging research field with potential for numerous applications in Nanotechnology, including quantum information processing and energy conversion. Of particular interest is the incorporation of *3d* transition metal ions (Mn, Co, etc...) whose *d*-shell electronic configurations imprint the nanocrystal with functional magnetic and optical properties.

We report on the optical and magnetic properties of Mn ions doped into colloidal PbS QDs. We observe a blue-shift of the photoluminescence (PL) and a decrease of the exciton *g*-factor upon increasing the Mn content, thus suggesting tunability of the dopant-carrier *s*,*p*-*d* exchange interaction.

For singly doped QDs, electron spin resonance (ESR) studies reveal the six hyperfine lines of isolated <sup>55</sup>Mn2+ ions. Long phase memory times ( $T_M \sim 10 \ \mu s$  at 5 K) up to near room temperature ( $T_M \sim 1 \ \mu s$  at 260K) were detected by pulsed-ESR methods after minimization of the major sources of decoherence. Finally, we use electron double resonance methods to detect the full Mn<sup>2+</sup> NMR spectrum and to drive Rabi oscillations implementing NOT and SWAP universal quantum gates.

In conclusion, Mn<sup>2+</sup> ions provide a means for tuning the optical and magnetic properties of QDs and represent a multilevel quantum bit system, *i.e.* a *qudit*, beyond traditional spin-*qubits* in QDs, for quantum computing application, whose states can be detected, coherently manipulated and potentially optically read-out via the *sp-d* interaction.

PhD students and all interested in the seminar are kindly invited to participate.